

CONTINUED PROSECUTION APPLICATION (CPA) UNDER 37 C.F.R. § 1.53(d) REQUEST TRANSMITTAL

303.522US1 Attorney Docket No.: Address to: Alan R. Reinberg First Named Inventor: **Commissioner for Patents** EL721276019US Express Mail No.: **Box CPA** Washington, D.C. 20231 0 Total Pages (if by fax):

This is a request for filing a continuation application under 37 CFR § 1.53(d) of prior application Serial No. 09/382,442, filed on August 25, 1999, entitled METHOD FOR REDUCING SINGLE BIT DATA LOSS IN A MEMORY CIRCUIT.

The above-identified prior application in which no abandonment of, or termination of, proceedings has occurred, is hereby expressly abandoned as of the filing date of this request for a CPA. Please use all the contents of the prior application file wrapper, including the drawings, as the basic papers for the new application. (37 CFR 1.53(b) must be used for continuation-in-part applications or for applications where the prior application is not to be abandoned.)

- Enter the amendment previously filed on _ under 37 CFR 1.116, but unentered, in the prior application.
- A Preliminary Amendment (4 pages) is enclosed. 2. X.
- This application is filed by fewer than all the inventors named in the prior application, 37 CFR 1.53(d)(4). 3. ___
 - **DELETE** the following inventor(s) named in the prior nonprovisional application:
 - The inventor(s) to be deleted are set forth on a separate sheet attached hereto.
- A new power of attorney is enclosed. 4. _
- Information Disclosure Statement is enclosed. 5. ___
 - Form(s) 1449
 - Copies of IDS Citations

05/25/2001 GTEFFERA 00000007 190743 09382442

710,00 CH 01 FC:131 02 FC:103 03 FC:102

108.00 CH 80.00 CH

TECHHOLOGY CENTER 2800

The filing fee is calculated below on the basis of the claims existing in the prior application as amended at 1 and 2 on the previous page:

No. Filed	No. Extra	Rate	Fee
	6	x 18 =	\$108.00
	1	x 80 =	\$80.00
			\$0.00
IMS PRESENTED			\$710.00
			\$898.00
	No. Filed 26 - 20 = 4 - 3 = AIMS PRESENTED	26 - 20 = 6 4 - 3 = 1 AIMS PRESENTED	No. Filed No. Extra 26 - 20 = 6 x 18 = 4 - 3 = 1 x 80 = AIMS PRESENTED

- Small Entity Status:
 - A small entity statement is enclosed.
 - A small entity statement was filed in the prior nonprovisional application and such status is still proper and desired.
 - Is no longer claimed.
- A check in the amount of <u>\$898.00</u> is attached to pay the filing fee.
- 8. X The Commissioner is hereby authorized to charge the required fee of \$898.00 to Deposit Account No. 19-0743.
- A petition for extension of time in the prior application is enclosed along with a check in the amount of \$0.00 to pay the extension fee.
- 10. X Other: A Clean Version of Pending Claims (4 pgs.)

SCHWEGMAN, LUNDBERG, WOESSNER & KLUTH, P.A. P.O. Box 2938, Minneapolis, MN 55402 (612-373-6900)

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This paper or fee is being deposited on the date indicated above with the United States Postal Service pursuant to 37 CFR 1.10, and is addressed to Box CPA, Commissioner for Patents, Washington, D. C. 20231.



PATENT

Group Art Unit: 2812

IN THE UNITED STATES PATENT AND TRADEMARK OFFICE Examiner: Richard A. Booth

Applicant:

Alan R. Reinberg

Serial No.:

09/382,442

CIRCUIT

Filed:

August 25, 1999

Title:

Docket: 303.522US1 METHOD FOR REDUCING SINGLE BIT DATA LOSS IN A MEMORY

PRELIMINARY AMENDMENT

Box CPA

Commissioner for Patents Washington, D.C. 20231

In response to the Final Office Action mailed February 21, 2001, please amend the application as follows:

IN THE CLAIMS

Please substitute the claim set in the appendix entitled Clean Version of Pending Claims for the previously pending claim set. Specific amendments to individual claims are detailed in the following marked up set of claims.

Please amend the claims as follows:

(Amended) A method for reducing random single bit data loss in a memory circuit 1. comprising:

providing a semiconductor layer having a surface;

heating the layer in an atmosphere comprising a Hydrogen isotope; and

fabricating a memory circuit comprising single bit data using the semiconductor layer wherein single bit data/loss is reduced.

(Amended) The method of daim 1 and further comprising fabricating a FLASH memory 3. circuit comprising single bit data using the semiconductor layer.

(Amended) The method of claim 7 and further comprising forming a film comprising 8. Hydrogen isotope adjacent to the gate region of the memory circuit in order to reduce single bit data loss.